### **Philips Semiconductors**

**Product specification** 

# Damper diode fast, high-voltage

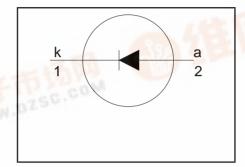
BY329-1500, BY329-1500S

### **FEATURES**

- Low forward volt drop
- Fast switching
- Soft recovery characteristicHigh thermal cycling performance
- Low thermal resistance

### **SYMBOL**

WWW.DZSC.



### QUICK REFERENCE DATA

$$V_R = 1500 \text{ V}$$
 $V_F \le 1.35 \text{ V} / 1.5 \text{ V}$ 
 $I_{F(peak)} = 6 \text{ A (f} = 16 \text{ kHz)}$ 
 $I_{F(peak)} = 6 \text{ A (f} = 70 \text{ kHz)}$ 
 $I_{FSM} \le 75 \text{ A}$ 
 $t_{rr} \le 230 \text{ ns} / 160 \text{ ns}$ 

# **GENERAL DESCRIPTION**

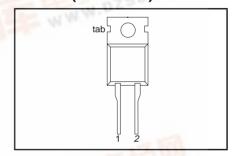
Glass-passivated double diffused rectifier diode featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The device is intended for use in TV receivers and PC monitors.

The BY329 series is supplied in the conventional leaded SOD59 (TO220AC) package.

# **PINNING**

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

# SOD59 (TO220AC)



# LIMITING VALUES

Limiting values accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RSM}$	Peak non-repetitive peak reverse voltage	五回 日 二	-	1500	V
$V_{RRM}$	Peak repetitive reverse voltage	C.COM	-	1500	V
$V_{RWM}$	Crest working reverse voltage		-	1300	V
190	THE	BY329		-1500 -1500S	
I <sub>F(peak)</sub>	Peak working forward current	f = 16 kHz f = 70 kHz	-	6 - 6	A A
I <sub>FRM</sub>	Peak repetitive forward current	$t = 25 \mu s; \ \delta = 0.5; \ T_{mb} \le 123 \ ^{\circ}C$	古田	14 C CO	Α
I <sub>F(RMS)</sub>	RMS forward current		- W	11	Α
I <sub>FSM</sub>	Peak non-repetitive forward current	t = 10 ms sinusoidal; T <sub>i</sub> = 150 °C prior to surge; with reapplied V <sub>RWM(max)</sub>	1	75	Α
$egin{array}{c} T_{ ext{stg}} \ T_{ ext{j}} \end{array}$	Storage temperature Operating junction temperature	RWM(max)	-40 -	150 150	ο°C

### THERMAL RESISTANCES

df.dzsc.com

	SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	R <sub>th j-mb</sub>	Thermal resistance junction to		-	-	2.0	K/W
0 ):	R <sub>th j</sub>	mounting base Thermal resistance junction to ambient	in free air	-	60	-	K/W

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BY329-1500, BY329-1500S

# STATIC CHARACTERISTICS

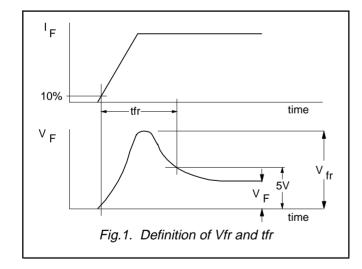
T<sub>i</sub> = 25 °C unless otherwise stated

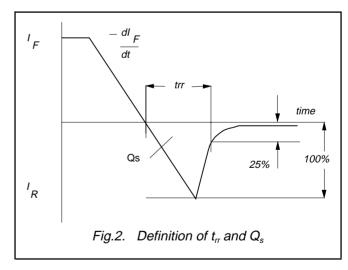
SYMBOL	PARAMETER	CONDITIONS	TY	Έ.	M	AX.	UNIT
		BY329	1500	1500S	1500	1500S	
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 6.5 A I <sub>F</sub> = 6.5 A; T <sub>i</sub> = 125 °C	1.1 1.05	1.3 1.2	1.45 1.35	1.6 1.5	V
I <sub>R</sub>	Reverse current	V <sub>R</sub> = 1300 V V <sub>R</sub> = 1300 V; T <sub>i</sub> = 125 °C	-	250 1	-	250 1	μA mA

# **DYNAMIC CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP.		M	UNIT	
		BY329	1500	1500S	1500	1500S	
t <sub>rr</sub>	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ $dI_F/dt = 50 \text{A}/\mu \text{s}$	0.18	0.13	0.23	0.16	μs
$egin{array}{c} Q_s \ V_{fr} \ t_{fr} \end{array}$	Reverse recovery charge Peak forward recovery voltage Forward recovery time	$I_F = 2 \text{ A}; -dI_F/dt = 20 \text{ A/}\mu\text{s}$ $I_F = 6.5 \text{A}; dI_F/dt = 50 \text{A/}\mu\text{s}$ $I_F = 6.5 \text{A}; dI_F/dt = 50 \text{A/}\mu\text{s}$	1.6 17 210	0.7 23 220	2.0 30 300	0.95 40 320	μC V ns





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# BY329-1500, BY329-1500S

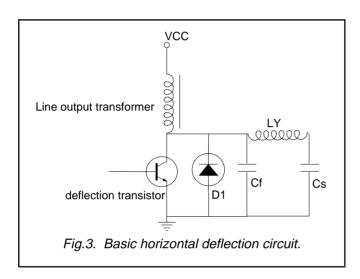


Fig.6. BY329-1500S Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

Maximum pulse width / us

100

| Deptide | Dep

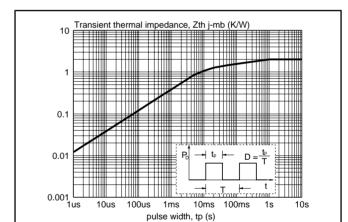


Fig.4. Maximum allowable pulse width t<sub>p</sub> versus line frequency; Basic horizontal deflection circuit.

Fig.7. Transient thermal impedance  $Z_{th} = f(t_p)$ 

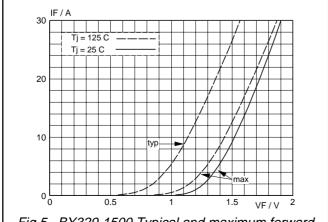
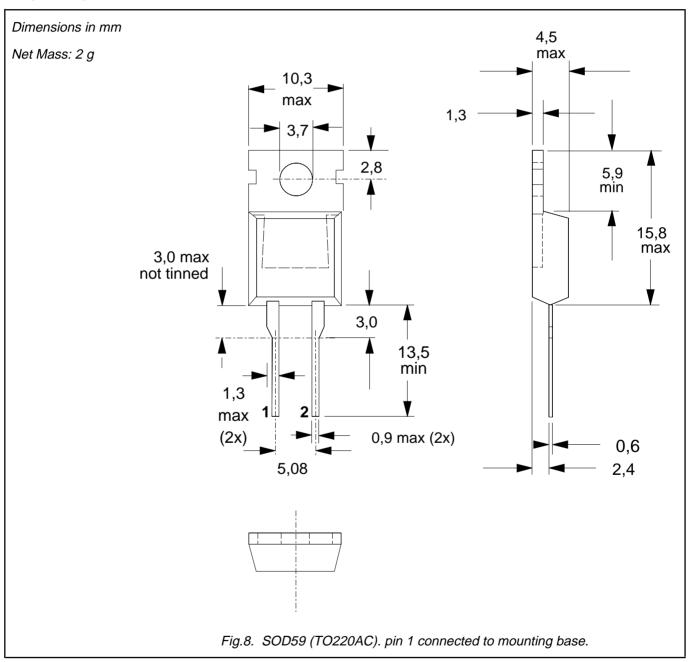


Fig.5. BY329-1500 Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

Damper diode fast, high-voltage BY329-1500, BY329-1500S

# **MECHANICAL DATA**



- Refer to mounting instructions for TO220 envelopes.
   Epoxy meets UL94 V0 at 1/8".

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# **DEFINITIONS**

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification This data sheet contains final product specifications.				
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#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

# **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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